



# 安徽富信半导体科技有限公司

ANHUI FOSAN SEMICONDUCTOR TECHNOLOGY CO., LTD.

DB3W

## SOD-123FL Trigger Diode 触发二极管

### ■Features 特点

Bidirectional Trigger 双向触发

Thyristor phase control 可控硅导通角控制

For lamp-dimming, universal-motor speed controls

用于台灯调光及无刷马达速度控制

Marking 印字: DB3



### ■Maximum Rating 最大额定值

( $T_A=25^\circ\text{C}$  unless otherwise noted 如无特殊说明, 温度为  $25^\circ\text{C}$ )

| Characteristic 特性参数   | Symbol 符号       | Rating 额定值     | Unit 单位 |
|---|-----------------|----------------|---------|
| Repetitive Peak On-state Current@ $t_p=20\mu\text{s}, f=100\text{Hz}$<br>重复峰值通态电流 | $I_{TRM}$       | 2              | A       |
| Power Dissipation 耗散功率  | $P_D$           | 150            | mW      |
| Thermal Resistance Junction-Ambient 结到环境热阻  | $R_{\theta JA}$ | 833            | °C/W    |
| Junction/Storage Temperature 结温/储藏温度  | $T_J, T_{stg}$  | -40 to +125 °C | °C      |

### ■Electrical Characteristics 电特性

( $T_A=25^\circ\text{C}$  unless otherwise noted 如无特殊说明, 温度为  $25^\circ\text{C}$ )

| Characteristic 特性参数  | Symbol 符号            | Min 最小值 | Max 最大值 | Unit 单位       |
|--|----------------------|---------|---------|---------------|
| Breakover Voltage 转折电压<br>@ $C = 22 \text{ nF}$ , see diagram 1                        | $V_{BO}$             | 28      | 36      | V             |
| Breakover Voltage Symmetry 转折电压偏差@ $C = 22 \text{ nF}$ , see diagram 1                 | $[+V_{BO} - V_{BO}]$ |         | 3       | V             |
| Dynamic Breakover Voltage 动态转折电压@ $\Delta I = [I_{BO} \text{ to } IF = 10 \text{ mA}]$ | $ \Delta V \pm $     | 5       |         | V             |
| Output Voltage 输出电压<br>See diagram 2   | $V_O$                | 5       |         | V             |
| Breakover Current 转折电流<br>@ $C = 22 \text{ nF}$  | $I_{BO}$             |         | 50      | $\mu\text{A}$ |
| Leakage Current<br>@ $V_B=0.5V_{BO}$   | $I_B$                |         | 10      | $\mu\text{A}$ |
| Rise Time 上升时间<br>See diagram 3  | $Tr$                 |         | 2       | $\mu\text{S}$ |

## ■ Typical Characteristic Curve 典型特性曲线

Diagram1: current-voltage characteristic

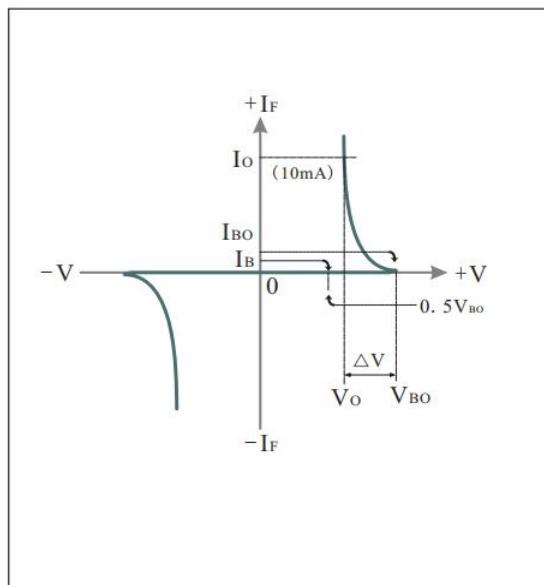


Fig.1: Power dissipation versus ambient temperature(maximum values)

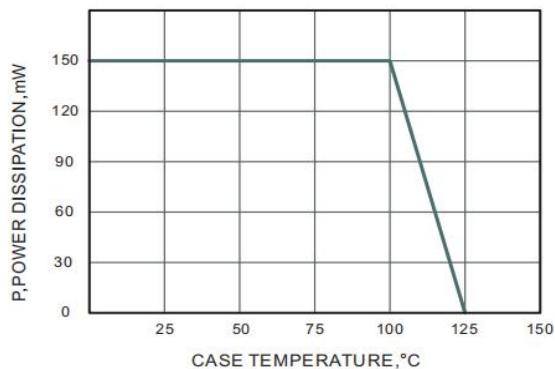


Diagram2: Test circuit for output voltage

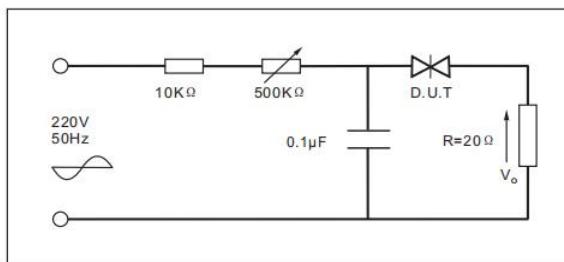


Diagram3: Test circuit see Fig.2. Adjust R for Ip=0.5A

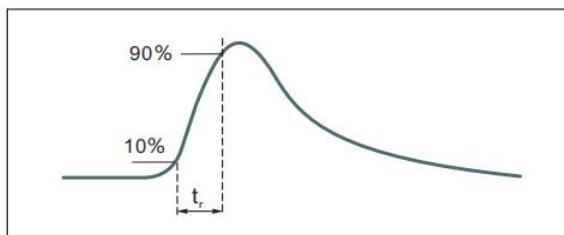


Fig.2: Power dissipation versus ambient temperature(maximum values)

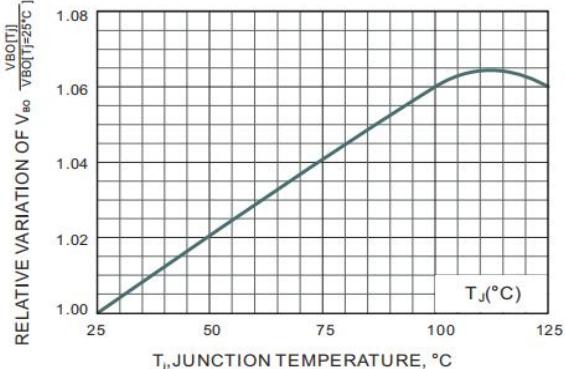
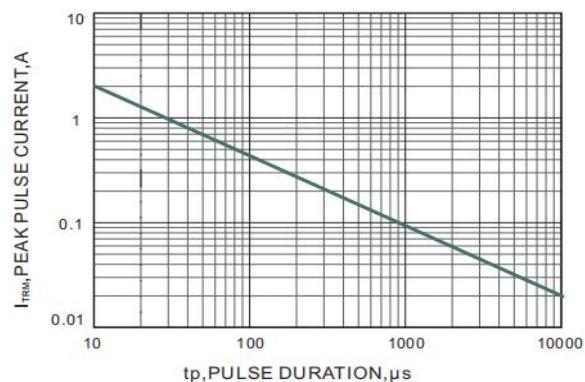
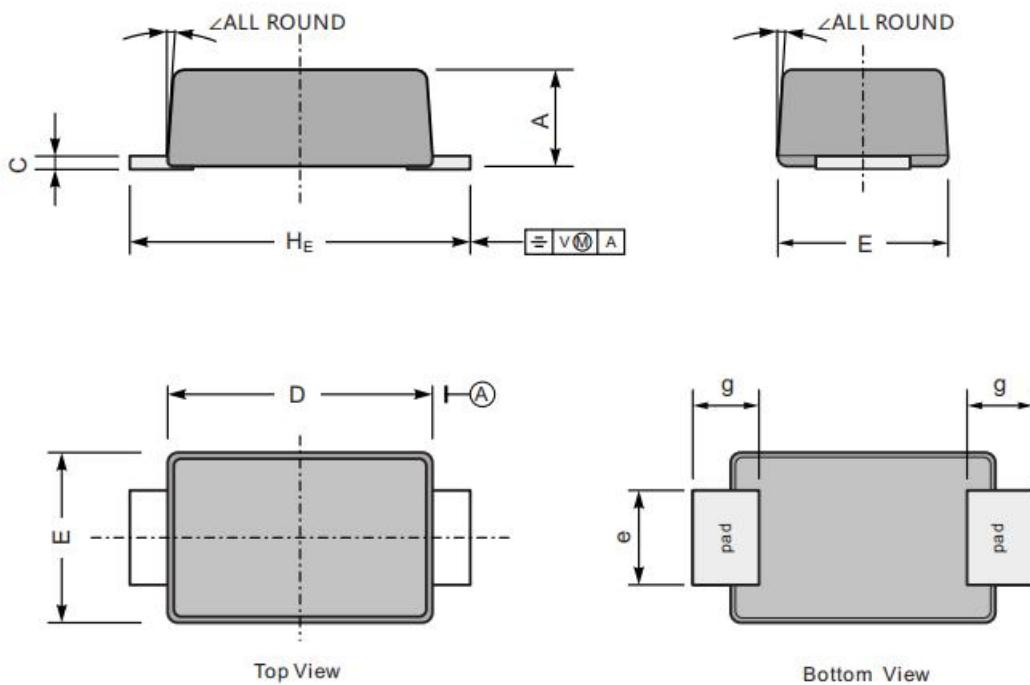


Fig.3: Power dissipation versus ambient temperature(maximum values)



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■ Dimension 外形封装尺寸



| UNIT |     | A   | C    | D   | E   | e   | g   | H <sub>E</sub> | $\angle$  |
|------|-----|-----|------|-----|-----|-----|-----|----------------|-----------|
| mm   | max | 1.1 | 0.20 | 2.9 | 1.9 | 1.1 | 0.9 | 3.8            | $7^\circ$ |
|      | min | 0.9 | 0.12 | 2.6 | 1.7 | 0.8 | 0.7 | 3.5            |           |
| mil  | max | 43  | 7.9  | 114 | 75  | 43  | 35  | 150            | $7^\circ$ |
|      | min | 35  | 4.7  | 102 | 67  | 31  | 28  | 138            |           |